

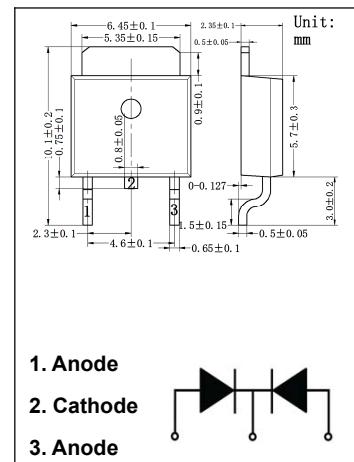
TO-252 Plastic-Encapsulate RECTIFIER

MBRD1060CT

10A SCHOTTKY BARRIER RECTIFIER

Features

- Low power loss, high efficiency.
- High surge capacity
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- Metal silicon junction, majority carrier conduction.
- High current Capability, low forward voltage drop.
- Guard ring for over voltage protection.



Maximum Ratings ($T_a=25^\circ\text{C}$ unless otherwise specified)

| Symbol | Parameter | Value | Unit |
|-------------|---------------------------------------------------------------------------------------------------|-------------|------|
| V_{RRM} | Drain-Source voltage | 60 | V |
| V_{RMS} | Maximum RMS Voltage | 42 | V |
| $V_{R(DC)}$ | Maximum DC Blocking Voltage | 60 | V |
| $I_{F(AV)}$ | Drain Current | 10 | A |
| I_{FSM} | Peak Forward Surge Current: 8.3ms single half sine-wave superimposed on rated load (JEDEC method) | 150 | A |
| V_F | Maximum Forward Voltage @ $I_F=10\text{A}$ | 0.72 | A |
| I_R | Maximum DC Reverse Current $T_j=25^\circ\text{C}$ $T_j=125^\circ\text{C}$ | 0.1 20 | mA |
| T_J | Junction Temperature(MAX) | 150 | °C |
| T_{STG} | Storage Temperature | -55 to +150 | °C |
| $R_{θJC}$ | Typical Thermal Resistance | 1.4 | °C/W |

Typical Characteristics

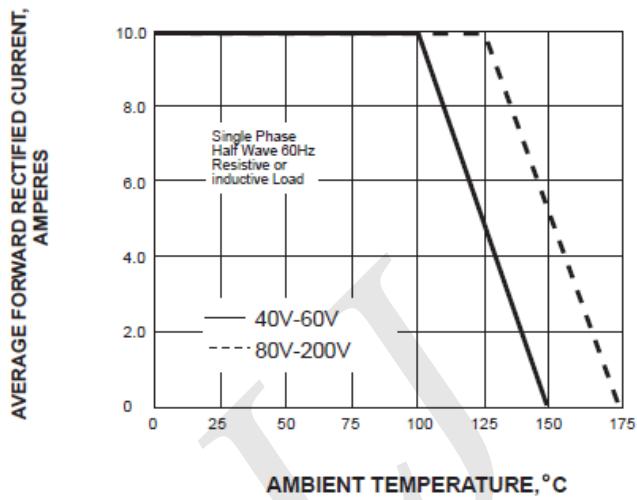


Fig.1 FORWARD CURRENT ERATING CURVE

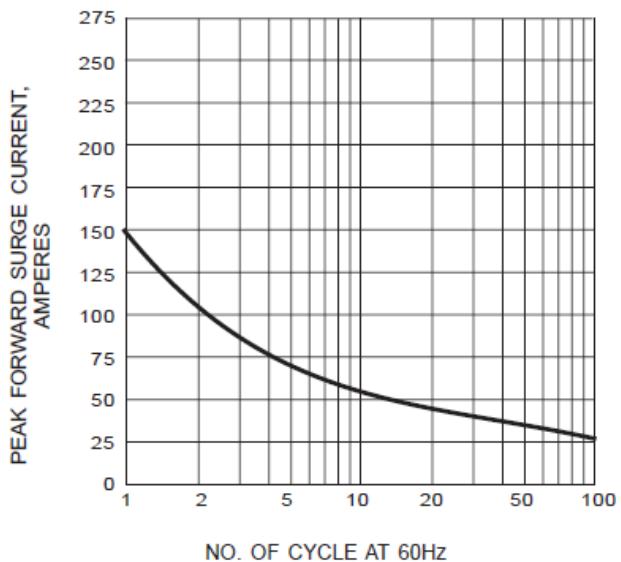


Fig.2 MAXIMUM NON-REPETITIVE SURGE CURRENT

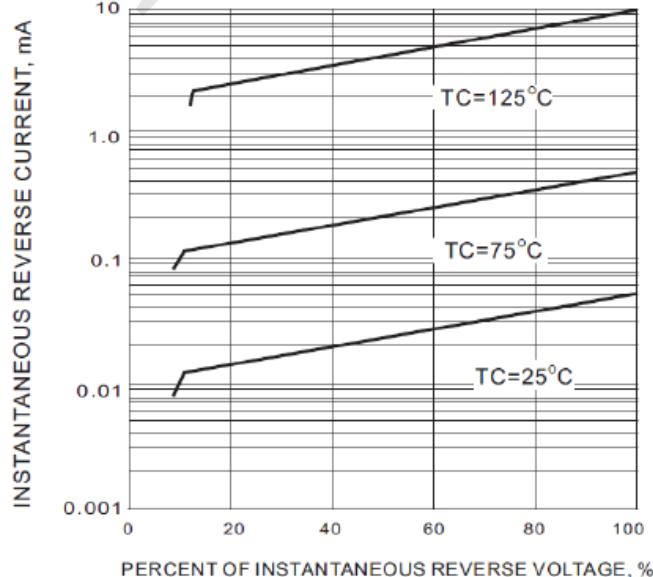


Fig.3 TYPICAL REVERSE CHARACTERISTIC

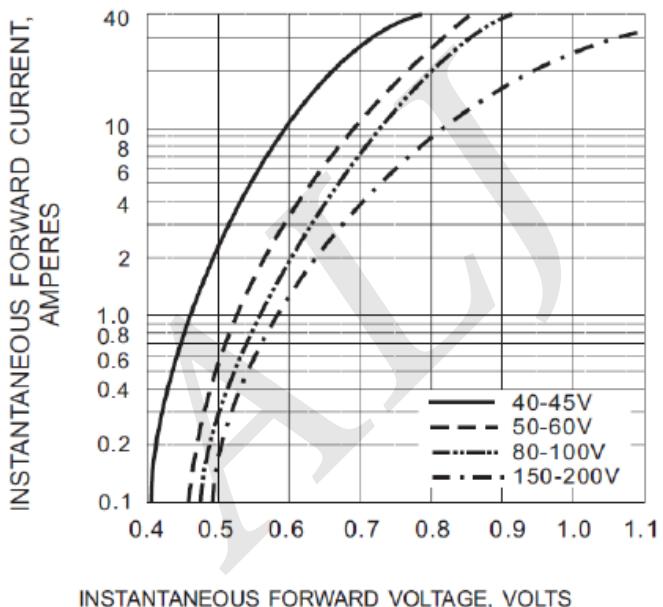


Fig.4 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTIC